



## SMAF Plastic-Encapsulate Diodes

### RS2AF THRU RS2MF Fast Recovery Rectifier Diodes

#### Features

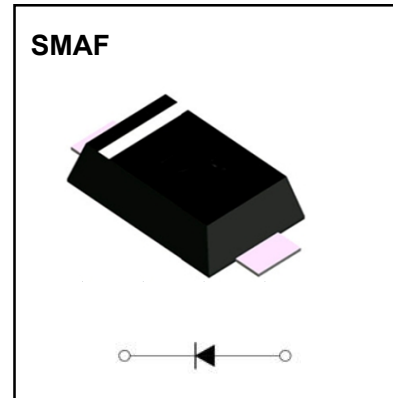
- $I_{F(AV)}$  2A
- $V_{RRM}$  50V-1000V
- High surge current capability
- Polarity: Color band denotes cathode

#### Applications

- Rectifier

#### Marking

- RS2X  
X : From A To M



#### Limiting Values(Absolute Maximum Rating)

Item	Symbol	Unit	Test Conditions	RS2						
				AF	BF	DF	GF	JF	KF	MF
Repetitive Peak Reverse Voltage	$V_{RRM}$	V		50	100	200	400	600	800	1000
Maximum RMS Voltage	$V_{RMS}$	V		35	70	140	280	420	560	700
Average Forward Current	$I_{F(AV)}$	A	60Hz Half-sine wave, Resistance load	2.0						
Surge(Non-repetitive)Forward Current	$I_{FSM}$	A	60Hz Half-sine wave, 1 cycle, $T_a=25^\circ\text{C}$	60						
Operation Junction and Storage Temperature Range	$T_J, T_{STG}$	$^\circ\text{C}$		-55 ~ +150						

#### Electrical Characteristics ( $T=25^\circ\text{C}$ Unless otherwise specified)

Item	Symbol	Unit	Test Condition	RS2						
				AF	BF	DF	GF	JF	KF	MF
Peak Forward Voltage	$V_F$	V	$I_F=2.0A$	1.3						
Maximum reverse recovery time	$t_{rr}$	ns	$I_F=0.5A, I_R=1.0A, I_{rr}=0.25A$	150			250		500	
Peak Reverse Current	$I_{RRM1}$	$\mu\text{A}$	$V_{RM}=V_{RRM}$	$T_a=25^\circ\text{C}$						
	$I_{RRM2}$			$T_a=125^\circ\text{C}$						
Thermal Resistance(Typical)	$R_{\theta J-A}$	$^\circ\text{C}/\text{W}$	Between junction and ambient				68			
	$R_{\theta J-L}$		Between junction and terminal				8.5			
Typical junction capacitance	$C_J$	pF	Measured at 1MHz and applied reverse voltage of 4.0V D.C.				11			

#### Notes:

Thermal resistance from junction to ambient and from junction to lead mounted on FR4 PCB double sided copper mini pad

# Typical Characteristics

FIG.1: FORWARD CURRENT DERATING CURVE

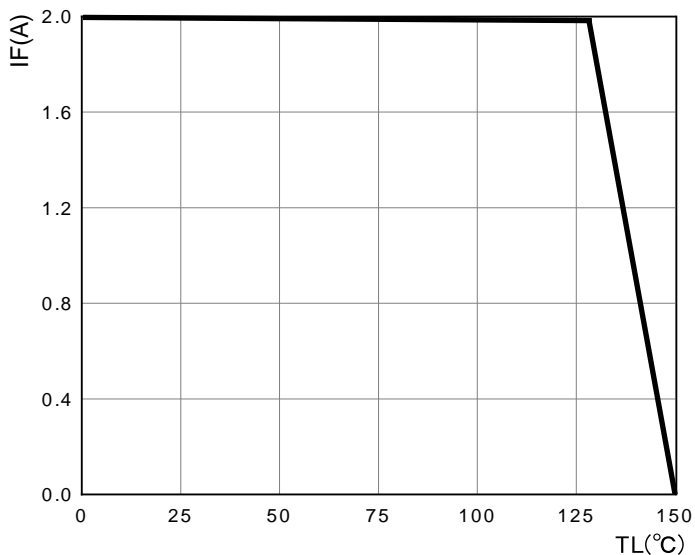


FIG.2: MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

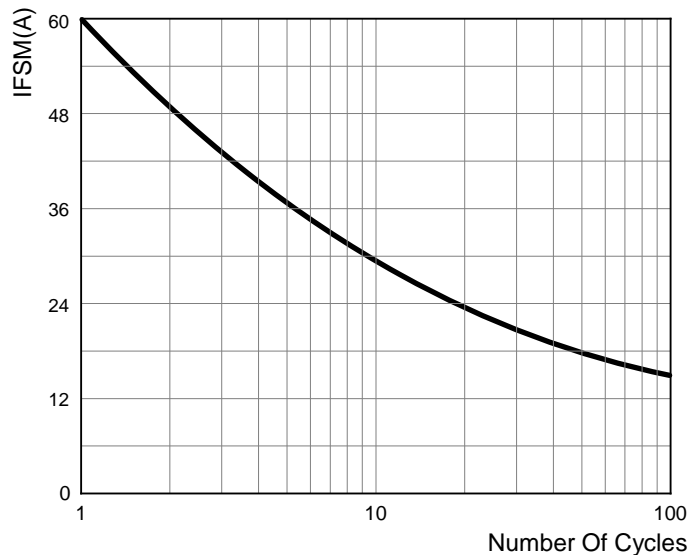


FIG.3 : TYPICAL FORWARD CHARACTERISTICS

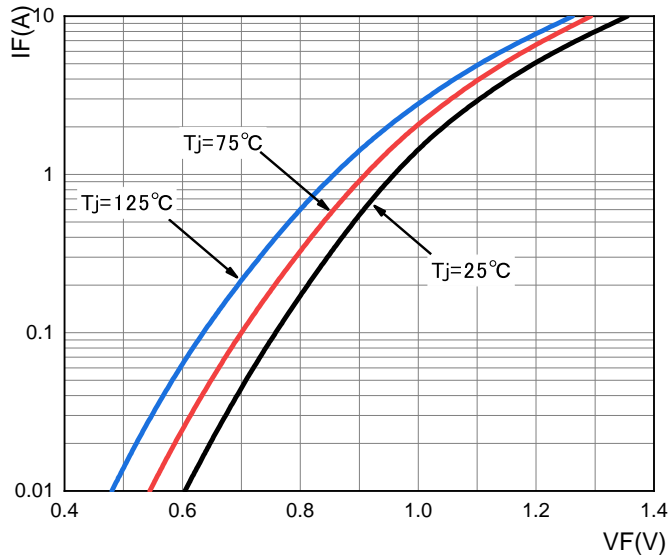
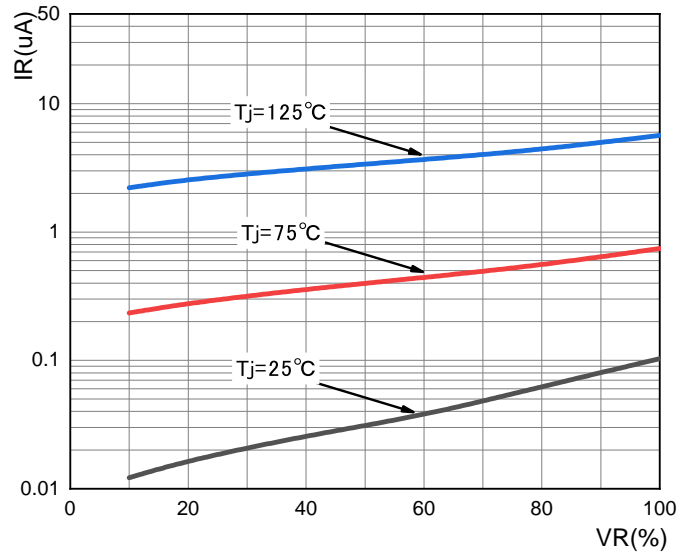
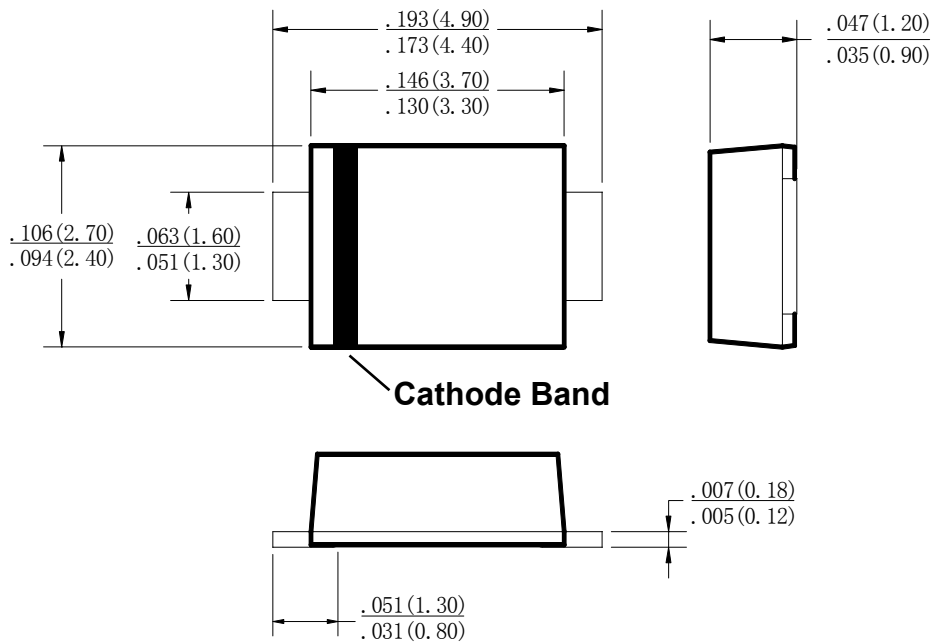


FIG.4 TYPICAL REVERSE CHARACTERISTICS

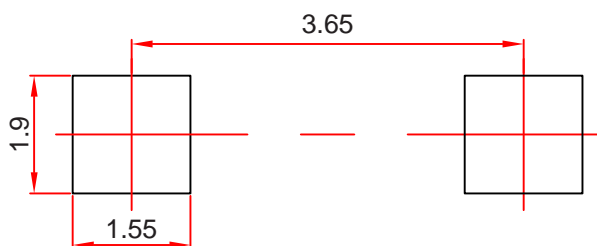


## SMAF Package Outline Dimensions



Dimensions in inches and (millimeters)

## SMAF Suggested Pad Layout



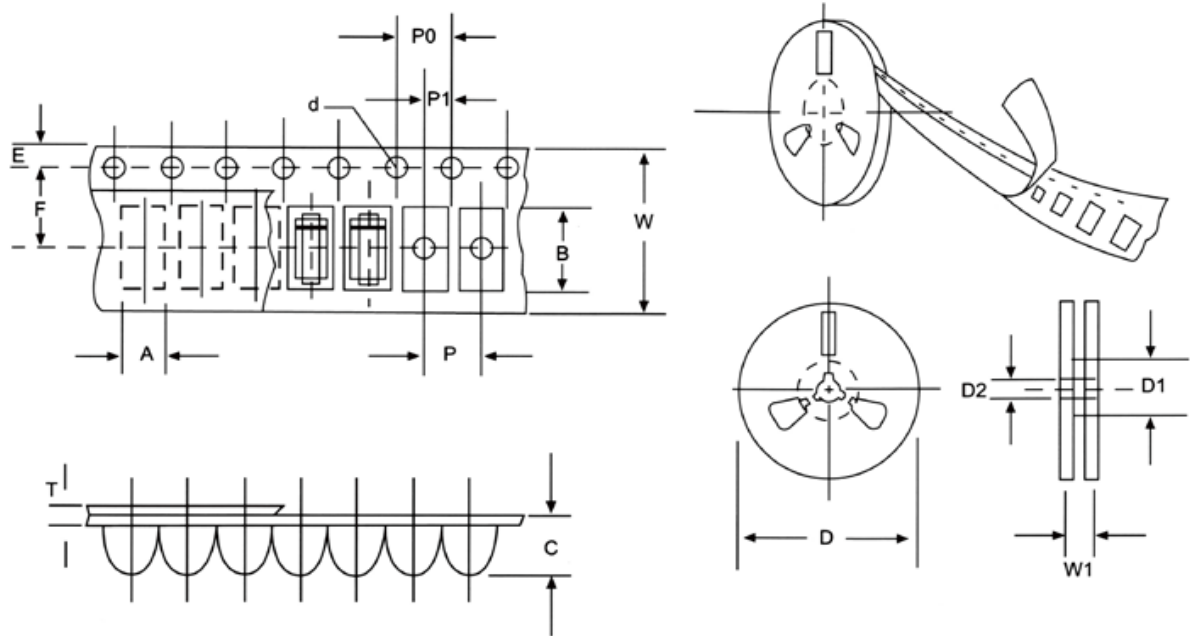
### Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.

### NOTICE

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## Reel Taping Specifications For Surface Mount Devices- SMAF



**FIG: CONFIGURATION OF SURFACE MOUNTED DEVICES TAPING**

ITEM	SYMBOL	SMAF mm(inch)
Carrier width	A	2.83+0.1(0.112+0.004)
Carrier length	B	4.90+0.1(0.193+0.004)
Carrier depth	C	1.45+0.1(0.057+0.004)
Sprocket hole	d	1.55+0.05(0.061+0.002)
Reel outside diameter	D	178+2.0(7.0+0.079)
Reel inner diameter	D1	54±1.0(2.13±0.039)
Feed hole diameter	D2	13+0.5(0.512+0.020)
Sprocket hole position	E	1.75+0.1(0.069+0.004)
Punch hole position	F	5.5+0.05(0.217+0.002)
Punch hole pitch	P	4.0+0.1(0.157+0.004)
Sprocket hole pitch	P0	4.0+0.1(0.157+0.004)
Embossment center	P1	2.0+0.1(0.079+0.004)
Total tape thickness	T	0.23-0.29(0.009-0.011)
Tape width	W	12.0+0.1(0.472+0.004)
Reel width	W1	16.8+2.0(0.661+0.079)

NOTE: Devices are packed in accordance with EIA standard RS-481-A and specification given above.